J309, J310

Preferred Device

JFET VHF/UHF Amplifiers

N-Channel — Depletion

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

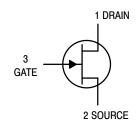
Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	25	Vdc
Gate-Source Voltage	V _{GS}	25	Vdc
Forward Gate Current	I _{GF}	10	mAdc
Total Device Dissipation @ T _A = 25°C Derate above = 25°C	P _D	350 2.8	mW mW/°C
Junction Temperature Range	TJ	-65 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



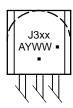
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



J3xx = Device Code

xx = 09 or 10

A = Assembly Location

Y = Year

WW = Work Week

= Pb-Free Package(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

J309, J310

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			I			
Gate – Source Breakdown Voltage ($I_G = -1.0 \mu Adc, V_{DS} = 0$)		V _{(BR)GSS}	-25	_	_	Vdc
Gate Reverse Current $(V_{GS} = -15 \text{ Vdc}, V_{DS} = 0, T_A = 25^{\circ}\text{C})$ $(V_{GS} = -15 \text{ Vdc}, V_{DS} = 0, T_A = +125^{\circ}\text{C})$		I _{GSS}	-	-	-1.0 -1.0	nAdc μAdc
Gate Source Cutoff Voltage (V _{DS} = 10 Vdc, I _D = 1.0 nAdc)	J309 J310	V _{GS(off)}	-1.0 -2.0	_ _	-4.0 -6.5	Vdc
ON CHARACTERISTICS						
Zero-Gate-Voltage Drain Current ⁽¹⁾ (V _{DS} = 10 Vdc, V _{GS} = 0)	J309 J310	I _{DSS}	12 24	- -	30 60	mAdc
Gate–Source Forward Voltage $(V_{DS} = 0, I_G = 1.0 \text{ mAdc})$		V _{GS(f)}	-	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS	•		•	•	•	
Common–Source Input Conductance (V _{DS} = 10 Vdc, I _D = 10 mAdc, f = 100 MHz)	J309 J310	Re(y _{is})	- -	0.7 0.5	- -	mmhos
Common–Source Output Conductance (V _{DS} = 10 Vdc, I _D = 10 mAdc, f = 100 MHz)		Re(y _{os})	-	0.25	_	mmhos
Common–Gate Power Gain (V _{DS} = 10 Vdc, I _D = 10 mAdc, f = 100 MHz)		G _{pg}	-	16	-	dB
Common–Source Forward Transconductance ($V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 100 \text{ MHz}$)		Re(y _{fs})	_	12	_	mmhos
Common–Gate Input Conductance ($V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 100 \text{ MHz}$)		Re(y _{ig})	_	12	-	mmhos
Common–Source Forward Transconductance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$	J309 J310	9 _{fs}	10000 8000	- -	20000 18000	μmhos
Common–Source Output Conductance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$		9 _{os}	-	-	250	μmhos
Common–Gate Forward Transconductance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$	J309 J310	9fg		13000 12000		μmhos
Common–Gate Output Conductance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$	J309 J310	gog	- -	100 150	- -	μmhos
Gate–Drain Capacitance $(V_{DS} = 0, V_{GS} = -10 \text{ Vdc}, f = 1.0 \text{ MHz})$		$C_{\sf gd}$	_	1.8	2.5	pF
Gate-Source Capacitance (V _{DS} = 0, V _{GS} = -10 Vdc, f = 1.0 MHz)		C _{gs}	-	4.3	5.0	pF
FUNCTIONAL CHARACTERISTICS						
Equivalent Short–Circuit Input Noise Voltage (V _{DS} = 10 Vdc, I _D = 10 mAdc, f = 100 Hz)		e _n	_	10	-	nV/√ Hz

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 3.0%.

ORDERING INFORMATION

Device	Package	Shipping [†]		
J309	TO-92			
J309G	TO-92 (Pb-Free)	1000 Units / Bulk		
J310	TO-92			
J310G	TO-92 (Pb-Free)	1000 Units / Bulk		
J310RLRP	TO-92			
J310RLRPG	TO-92 (Pb-Free)	2000 Units / Tape & Ammo Box		
J310ZL1	TO-92			
J310ZL1G	TO-92 (Pb-Free)	2000 Units / Tape & Ammo Box		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

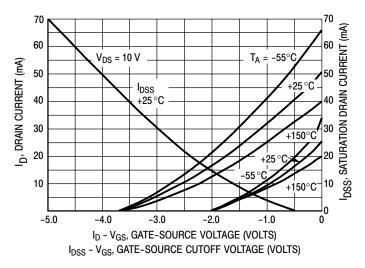


Figure 1. Drain Current and Transfer Characteristics versus Gate-Source Voltage

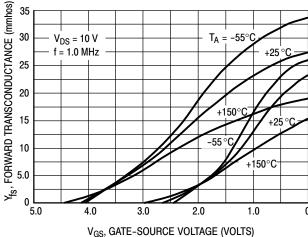


Figure 2. Forward Transconductance versus Gate-Source Voltage

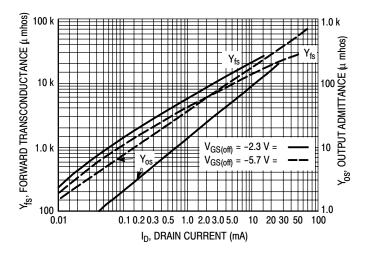


Figure 3. Common–Source Output
Admittance and Forward Transconductance
versus Drain Current

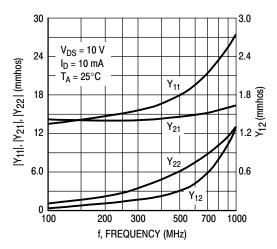


Figure 5. Common-Gate Y Parameter Magnitude versus Frequency

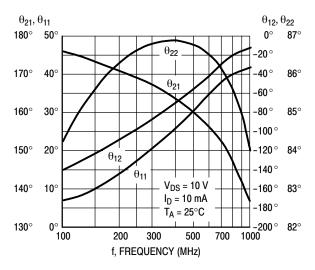


Figure 7. Common-Gate Y Parameter Phase-Angle versus Frequency

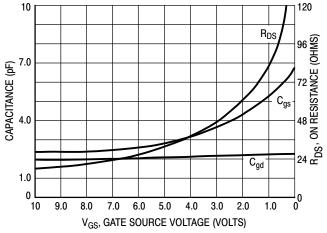


Figure 4. On Resistance and Junction Capacitance versus Gate-Source Voltage

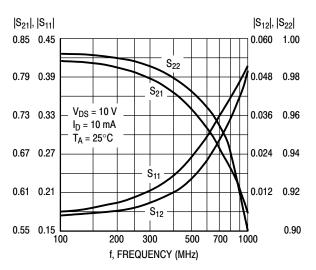


Figure 6. Common-Gate S Parameter Magnitude versus Frequency

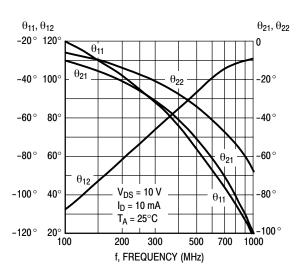
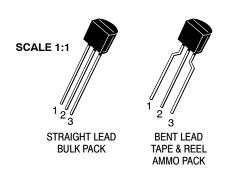


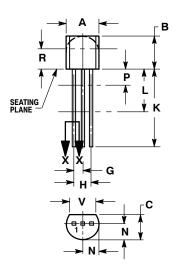
Figure 8. S Parameter Phase–Angle versus Frequency





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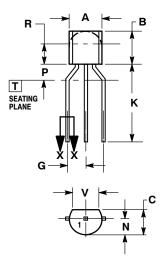


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R
 IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS		
DIM	MIN MAX		MIN	MAX		
Α	0.175	0.205	4.45	5.20		
В	0.170	0.210	4.32	5.33		
С	0.125	0.165	3.18	4.19		
D	0.016	0.021	0.407	0.533		
G	0.045	0.055	1.15	1.39		
Н	0.095	0.105	2.42	2.66		
J	0.015	0.020	0.39	0.50		
K	0.500		12.70			
L	0.250		6.35			
N	0.080	0.105	2.04	2.66		
Р		0.100		2.54		
R	0.115		2.93			
٧	0.135		3.43			



BENT LEAD TAPE & REEL AMMO PACK



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER

- AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS						
DIM	MIN	MAX					
Α	4.45	5.20					
В	4.32	5.33					
С	3.18	4.19					
D	0.40	0.54					
G	2.40	2.80					
J	0.39	0.50					
K	12.70						
N	2.04	2.66					
P	1.50	4.00					
R	2.93						
٧	3.43						

STYLES ON PAGE 2

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DATE 09 MAR 2007

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	
PIN 1. 2.	GATE	PIN 1.	SOURCE	PIN 1.	DRAIN	PIN 1.	BASE 1	2.	CATHODE
2.	ANODE CATHODE & ANODE	2.	GATE	2.	ANODE 1 GATE CATHODE 2	2.	EMITTER COLLECTOR BASE	2.	ANODE 1 CATHODE ANODE 2
2.	ANODE GATE	PIN 1. 2.	COLLECTOR	PIN 1.	ANODE CATHODE NOT CONNECTED	PIN 1.	GATE	PIN 1. 2.	NOT CONNECTED CATHODE ANODE
PIN 1. 2.	COLLECTOR EMITTER	PIN 1.	SOURCE GATE	PIN 1. 2.		PIN 1. 2.	EMITTER COLLECTOR/ANODE CATHODE	PIN 1. 2.	MT 1
	Vcc	PIN 1.	MT SUBSTRATE		CATHODE ANODE	PIN 1. 2.	NOT CONNECTED ANODE CATHODE	PIN 1. 2.	DRAIN
PIN 1. 2.	GATE	PIN 1. 2.	BASE COLLECTOR EMITTER	PIN 1. 2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT		

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